



DS5987 – 1 January 2011 (LN28008)

### FEATURES

- Double Side Cooling
- High Surge Capability

### KEY PARAMETERS

$V_{RRM}$	<b>6000V</b>
$I_{F(AV)}$	<b>630A</b>
$I_{FSM}$	<b>10500A</b>

### VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages $V_{RRM}$ V	Conditions
DRD630G60	6000	$V_{RSM} = V_{RRM} + 100V$
DRD630G58	5800	
DRD630G56	5600	
DRD630G52	5200	

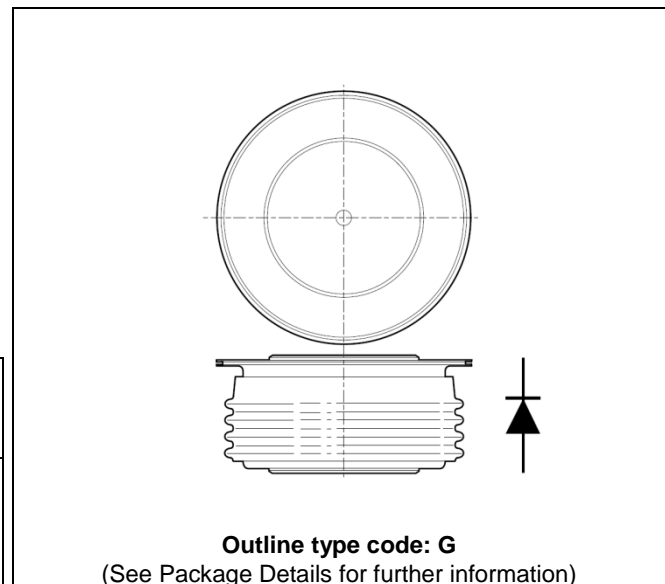


Fig. 1 Package outline

### ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

**DRD630G56** for a 5600V device

**CURRENT RATINGS**
**T<sub>case</sub> = 75°C unless stated otherwise**

Symbol	Parameter	Test Conditions	Max.	Units
<b>Double Side Cooled</b>				
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load	811	A
I <sub>F(RMS)</sub>	RMS value	-	1274	A
I <sub>F</sub>	Continuous (direct) on-state current	-	1172	A
<b>Single Side Cooled (Anode side)</b>				
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load	534	A
I <sub>F(RMS)</sub>	RMS value	-	839	A
I <sub>F</sub>	Continuous (direct) on-state current	-	727	A

**T<sub>case</sub> = 100°C unless stated otherwise**

Symbol	Parameter	Test Conditions	Max.	Units
<b>Double Side Cooled</b>				
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load	630	A
I <sub>F(RMS)</sub>	RMS value	-	990	A
I <sub>F</sub>	Continuous (direct) on-state current	-	900	A
<b>Single Side Cooled (Anode side)</b>				
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load	410	A
I <sub>F(RMS)</sub>	RMS value	-	644	A
I <sub>F</sub>	Continuous (direct) on-state current	-	550	A

**SURGE RATINGS**

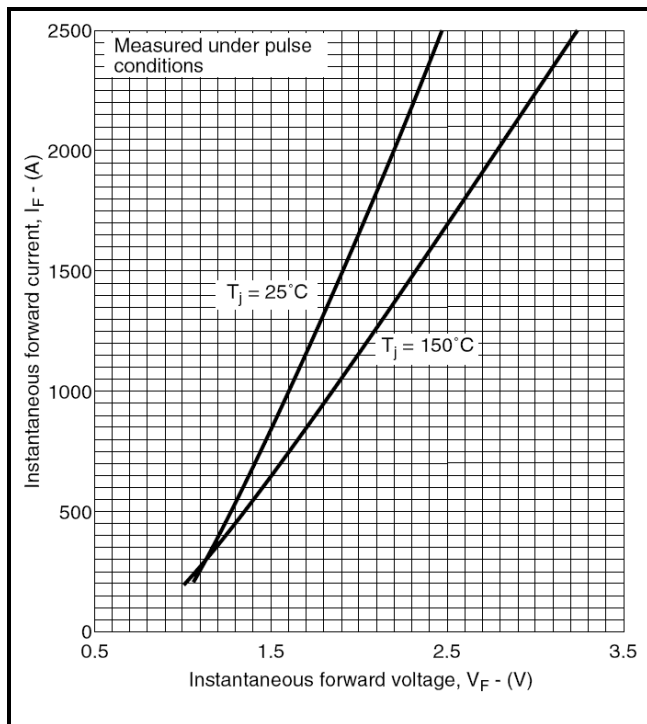
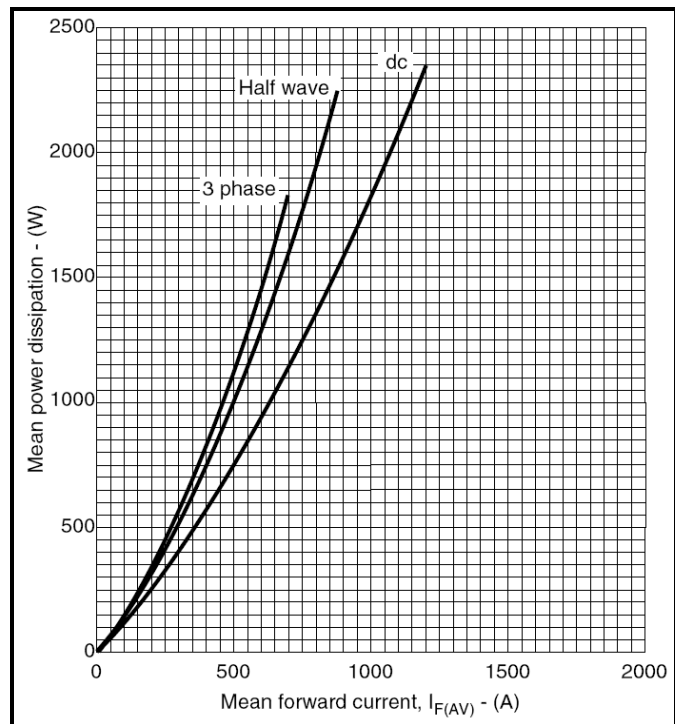
Symbol	Parameter	Test Conditions	Max.	Units
$I_{FSM}$	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 150^{\circ}C$	8.5	kA
$I^2t$	$I^2t$ for fusing	$V_R = 50\% V_{RRM} - 1/4$ sine	0.36	MA <sup>2</sup> s
$I_{FSM}$	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 150^{\circ}C$	10.5	kA
$I^2t$	$I^2t$ for fusing	$V_R = 0$	0.565	MA <sup>2</sup> s

**THERMAL AND MECHANICAL RATINGS**

Symbol	Parameter	Test Conditions	Min.	Max.	Units	
$R_{th(j-c)}$	Thermal resistance – junction to case	Double side cooled	DC	-	0.032	$^{\circ}C/W$
		Single side cooled	Anode DC	-	0.064	$^{\circ}C/W$
			Cathode DC	-	0.064	$^{\circ}C/W$
$R_{th(c-h)}$	Thermal resistance – case to heatsink	Clamping force 12kN	Double side	-	0.008	$^{\circ}C/W$
		(with mounting compound)	Single side	-	0.016	$^{\circ}C/W$
$T_{vj}$	Virtual junction temperature	On-state (conducting)	-	160	$^{\circ}C$	
		Reverse (blocking)	-	150	$^{\circ}C$	
$T_{stg}$	Storage temperature range		-55	175	$^{\circ}C$	
$F_m$	Clamping force		11.5	13.5	kN	

**CHARACTERISTICS**

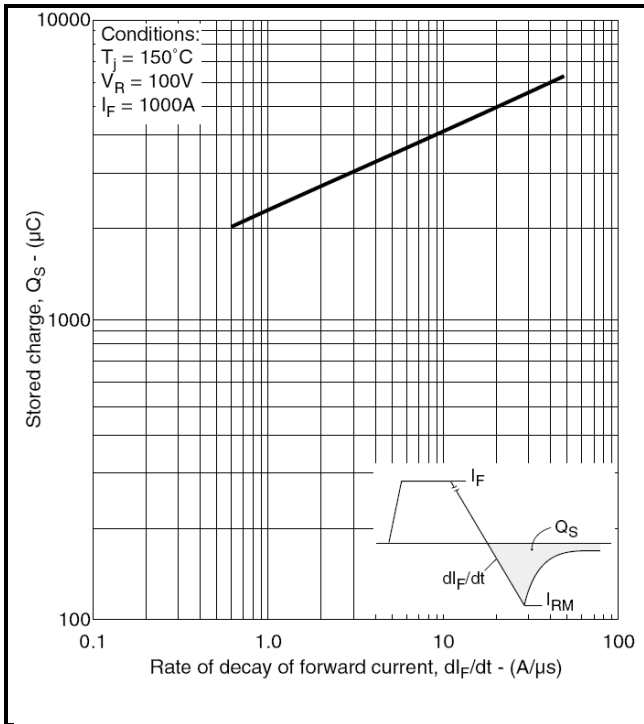
Symbol	Parameter	Test Conditions	Min.	Max.	Units
$V_{FM}$	Forward voltage	At 1800A peak, $T_{case} = 25^{\circ}C$	-	2.1	V
$I_{RM}$	Peak reverse current	At $V_{RRM}$ , $T_{case} = 150^{\circ}C$	-	75	mA
$Q_S$	Total stored charge	$I_F = 1000A$ , $dI_{RR}/dt = 3A/\mu s$	-	3000	$\mu C$
$I_{rr}$	Peak reverse recovery current	$T_{case} = 150^{\circ}C$ , $V_R = 100V$	-	90	A
$V_{TO}$	Threshold voltage	At $T_{vj} = 150^{\circ}C$	-	0.9	V
$r_T$	Slope resistance	At $T_{vj} = 150^{\circ}C$	-	0.93	$m\Omega$

**CURVES**

**Fig.2 Maximum (limit) on-state characteristics**

**Fig.3 Dissipation curves**
 **$V_{TM}$  EQUATION**

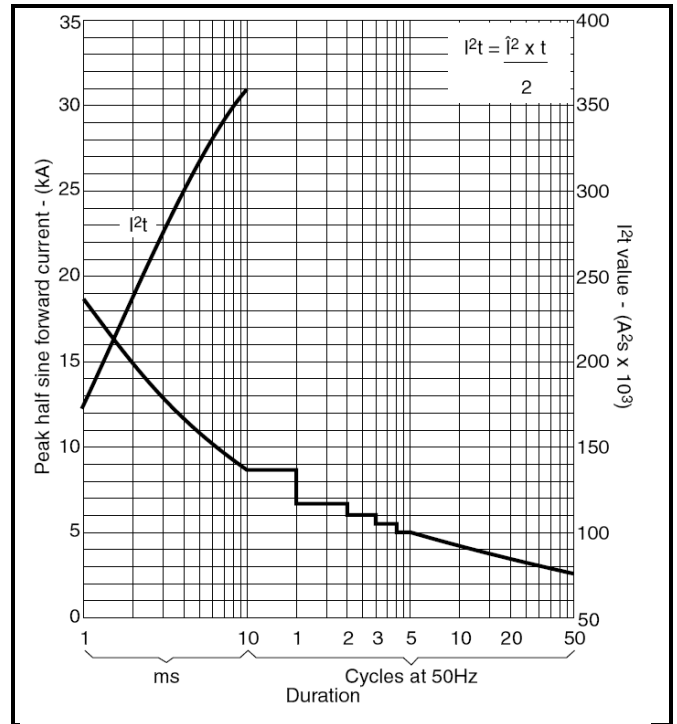
$$V_{TM} = A + B \ln(I_T) + C \cdot I_T + D \cdot \sqrt{I_T}$$

 Where  $A = 1.249986$ 
 $B = -0.17646$ 
 $C = 0.000524$ 
 $D = 0.041024$ 

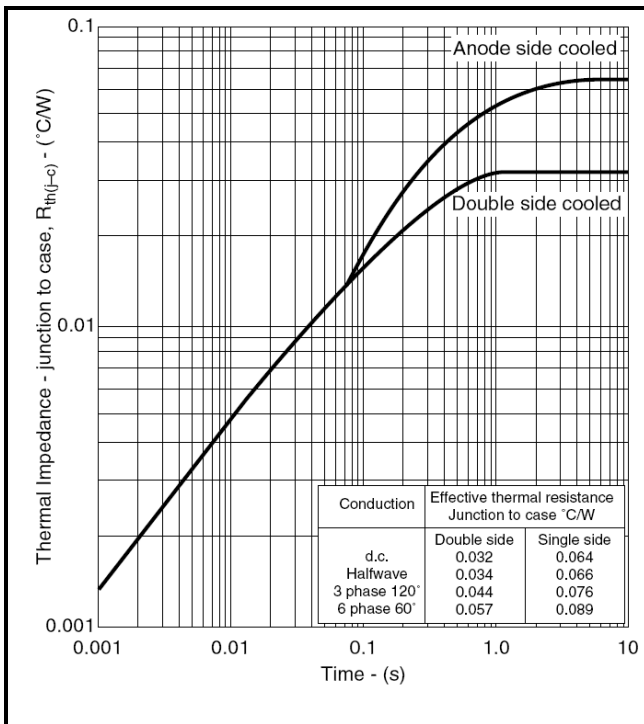
 these values are valid for  $T_j = 150^{\circ}C$  for  $I_F$  500A to 2500A



**Fig.4 Total stored charge**



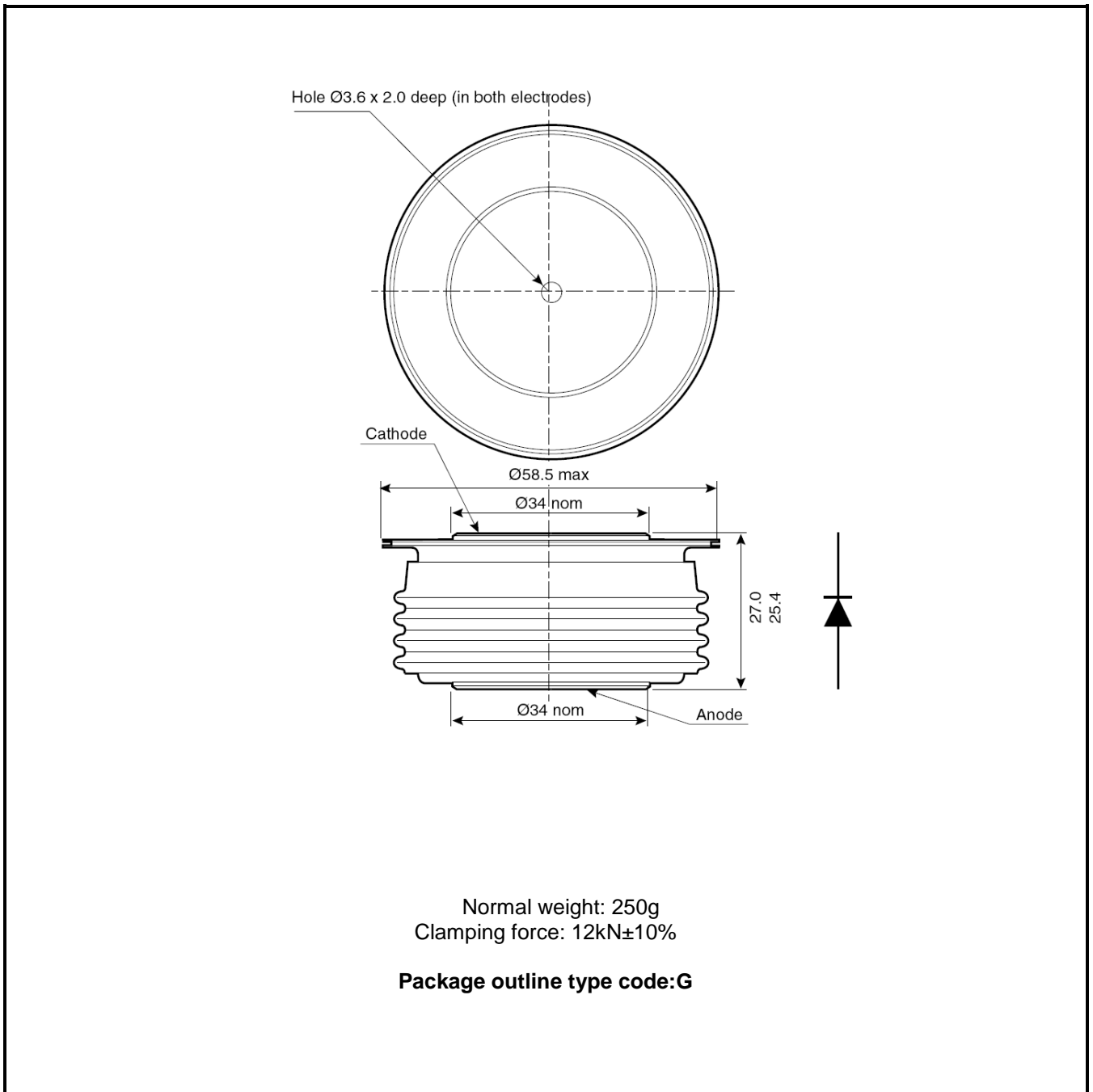
**Fig.5 Surge (non-repetitive) forward current vs time (with 50%  $V_{RRM}$  at  $T_{case} 150^\circ\text{C}$ )**



**Fig.6 Maximum (limit) transient thermal impedance-junction to case**

**PACKAGE DETAILS**

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



**Note:**  
 Some packages may be supplied with gate and or tags.

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**HEADQUARTERS OPERATIONS**

DYNEX SEMICONDUCTOR LIMITED  
Doddington Road, Lincoln, Lincolnshire, LN6 3LF  
United Kingdom.  
Phone: +44 (0) 1522 500500  
Fax: +44 (0) 1522 500550  
Web: <http://www.dynexsemi.com>

**CUSTOMER SERVICE**

Phone: +44 (0) 1522 502753 / 502901  
Fax: +44 (0) 1522 500020  
e-mail: [power\\_solutions@dynexsemi.com](mailto:power_solutions@dynexsemi.com)